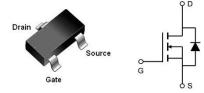
#### **Features**

- Low  $R_{DS(on)}$  @ $V_{GS}$ =4.5V
- 3.3V Logic Level Control
- N Channel SOT23 Package
- Pb-Free, RoHS Compliant

V <sub>(BR)DSS</sub>	$R_{DS(ON)}Typ$	I <sub>D</sub> Max
20V	28mΩ @ 4.5V	2.64
	32mΩ @ 3.3V	3.6A

## **Applications**

- Load Switch
- DC/DC Converter
- · Switching Circuits
- •LED Driver



## **Order Information**

SOT23

Product	Product Package		Packing	Min Unit Quantity	
SI2302	SOT23	A2SHB	3000PCS/Reel	3000PCS	

### **Absolute Maximum Ratings**

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Symbol	Parameter	Rating	Unit					
Common Ratings (Ta=25°C Unless Otherwise Noted)								
V <sub>GS</sub>	Gate-Source Voltage ±10							
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	20	V					
T <sub>J</sub>	Maximum Junction Temperature	150	°C					
T <sub>STG</sub>	Storage Temperature Range	-50 to 150	°C					
Mounted or	Mounted on Large Heat Sink							
I <sub>DM</sub>	Pulse Drain Current Tested⊕	18	А					
ı	Continuous Dusin Commental ( 4510)	T <sub>A</sub> =25°C	3.6					
l I <sub>D</sub>	Continuous Drain Current(V <sub>G</sub> s=4.5V)	T <sub>A</sub> =70°C	3.0	A				
$P_{D}$	M : B B: : ::	T <sub>A</sub> =25°C	1.2	W				
	Maximum Power Dissipation	T <sub>A</sub> =70°C	0.9					
R <sub>∂JA</sub>	Thermal Resistance Junction-Ambient	100	°C/W					

Symbol	Parameter	Condition	Min	Тур	Max	Unit			
Static Ele	Static Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated)								
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	Vgs=0V Ip=250μA	20			V			
	Zero Gate Voltage Drain Current(T₄=25°C)	VDS=20V, VGS=0V			1	μA			
I <sub>DSS</sub>	Zero Gate Voltage Drain Current(T <sub>A</sub> =125°C)	V <sub>D</sub> S=16V, V <sub>G</sub> S=0V			100	uA			
I <sub>GSS</sub>	Gate-Body Leakage Current	Vgs=±10V, Vps=0V			±100	nA			
$V_{\rm GS(TH)}$	Gate Threshold Voltage	Vɒs=Vgs, Iɒ=250μA	0.4	0.6	1.0	V			
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance②	Vgs=4.5V, ID=4A		28	35	mΩ			
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance②	Vgs=3.3V, ID=2A		32	40	mΩ			
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance②	Vgs=2.5V, ID=1A		36	45	mΩ			
Dynamic I	Electrical Characteristics @ TJ = 25°C (u	ınless otherwise stated	l)		•				
C <sub>iss</sub>	Input Capacitance			280		pF			
C <sub>oss</sub>	Output Capacitance	VDS=10V, VGS=0V, f=1MHz		46		pF			
C <sub>rss</sub>	Reverse Transfer Capacitance			42		pF			
$Q_g$	Total Gate Charge	V <sub>DS</sub> =10V		4.7		nC			
$Q_{gs}$	Gate Source Charge	ID=3A,		0.6		nC			
$Q_{gd}$	Gate Drain Charge	Vgs=5V		1.7		nC			
	Characteristics		•	•					
t <sub>d(on)</sub>	Turn on Delay Time			11		ns			
t <sub>r</sub>	Turn on Rise Time	VDD=10V, ID=4A,		35		ns			
$t_{d(off)}$	Turn Off Delay Time	Rg=3.3Ω, Vgs=4.5V	-	25		ns			
t <sub>f</sub>	Turn Off Fall Time	v 65–4.0v		32		ns			
Source Dr	rain Diode Characteristics								
I <sub>SD</sub>	Source drain current(Body Diode)	T <sub>A</sub> =25°C			1.8	А			
$V_{\scriptscriptstyle{SD}}$	Forward on voltage②	Tj=25°C, IsD=2A, VGS=0V		0.74	1.2	V			

#### Notes:

 $<sup>\, \</sup>odot \,$  Pulse width limited by maximum allowable junction temperature

 $<sup>@ \ \</sup>text{Pulse test} \ ; \ \text{Pulse width} \quad 300 \mu \text{s}, \ \text{duty cycle} \quad 2\%.$ 

# **Typical Characteristics**

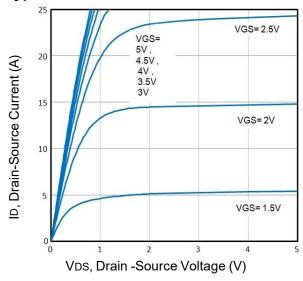


Fig1. Typical Output Characteristics

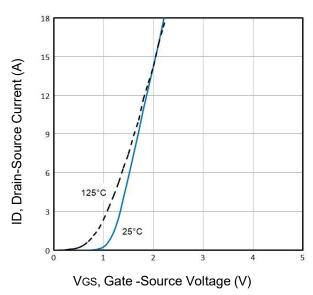


Fig3. Typical Transfer Characteristics

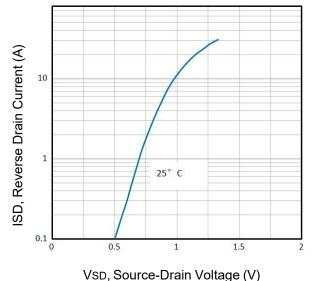


Fig5. Typical Source-Drain Diode Forward Voltage

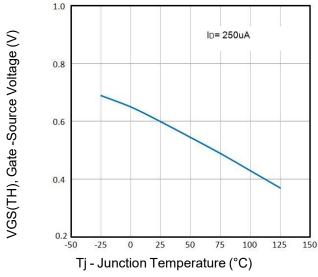


Fig2. Normalized Threshold Voltage Vs. Temperature

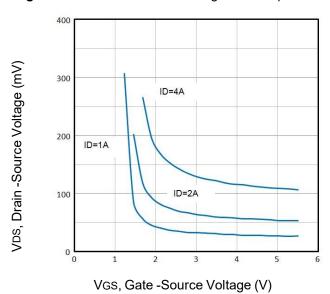


Fig4. Drain -Source Voltage vs Gate -Source Voltage

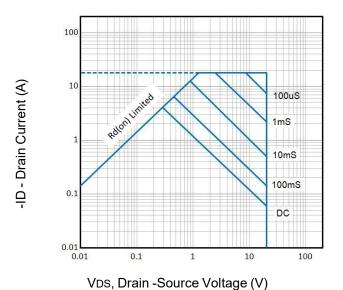
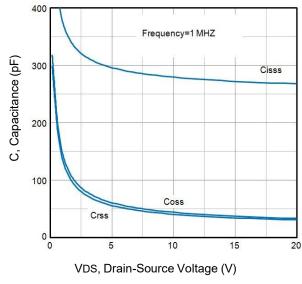
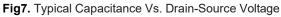


Fig6. Maximum Safe Operating Area

# **Typical Characteristics**





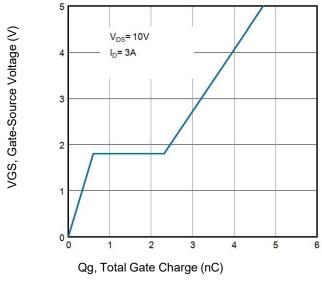


Fig8. Typical Gate Charge Vs. Gate-Source Voltage

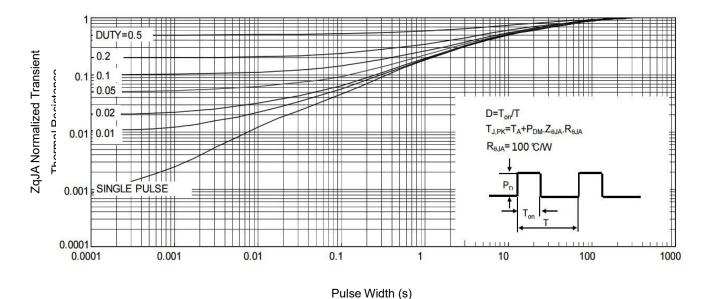


Fig9. Normalized Maximum Transient Thermal Impedance

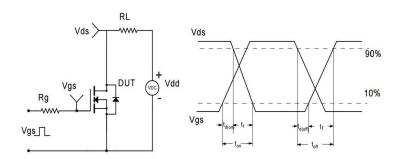
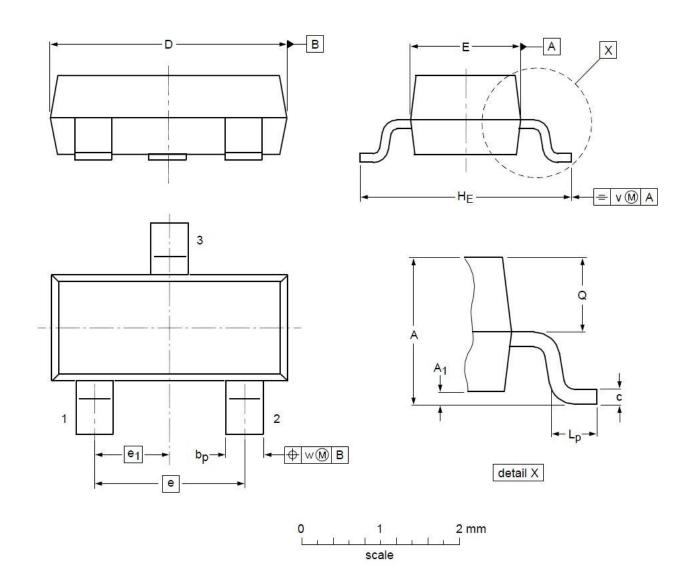


Fig10. Switching Time Test Circuit and waveforms

# **SOT23 Mechanical Data**



# **DIMENSIONS** ( unit : mm )

Symbol	Min	Тур	Max	Symbol	Min	Тур	Max
Α	0.90	1.01	1.15	<b>A</b> 1	0.01	0.05	0.10
bp	0.30	0.42	0.50	С	0.08	0.13	0.15
D	2.80	2.92	3.00	E	1.20	1.33	1.40
е		1.90		<b>e</b> 1		0.95	
HE	2.25	2.40	2.55	Lp	0.30	0.42	0.50
Q	0.45	0.49	0.55	v		0.20	
w		0.10					